

Sensors, Signals and Noise

COURSE OUTLINE

- Introduction
- Signals and Noise
- **Filtering: LPF2 Switched-Parameter Filters**
- Sensors and associated electronics



Switched-parameter filters

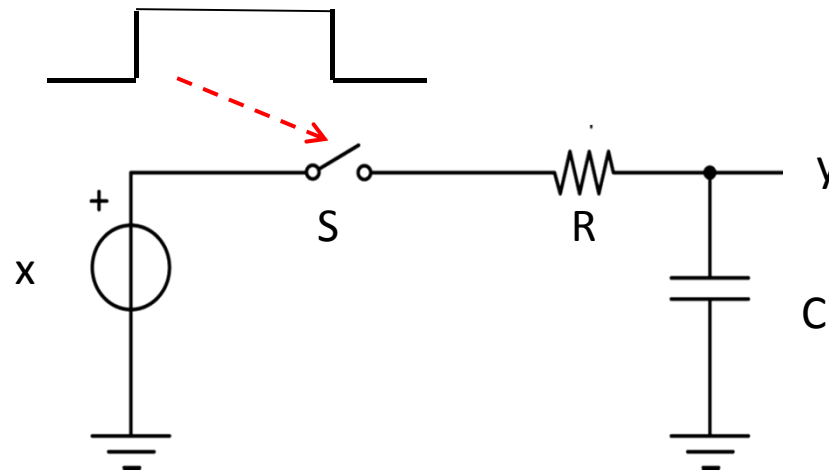
- Switched-parameter RC low-pass filters
- Sample and Hold S&H
- Gated Integrator GI



Switched-parameter RC low-pass filters



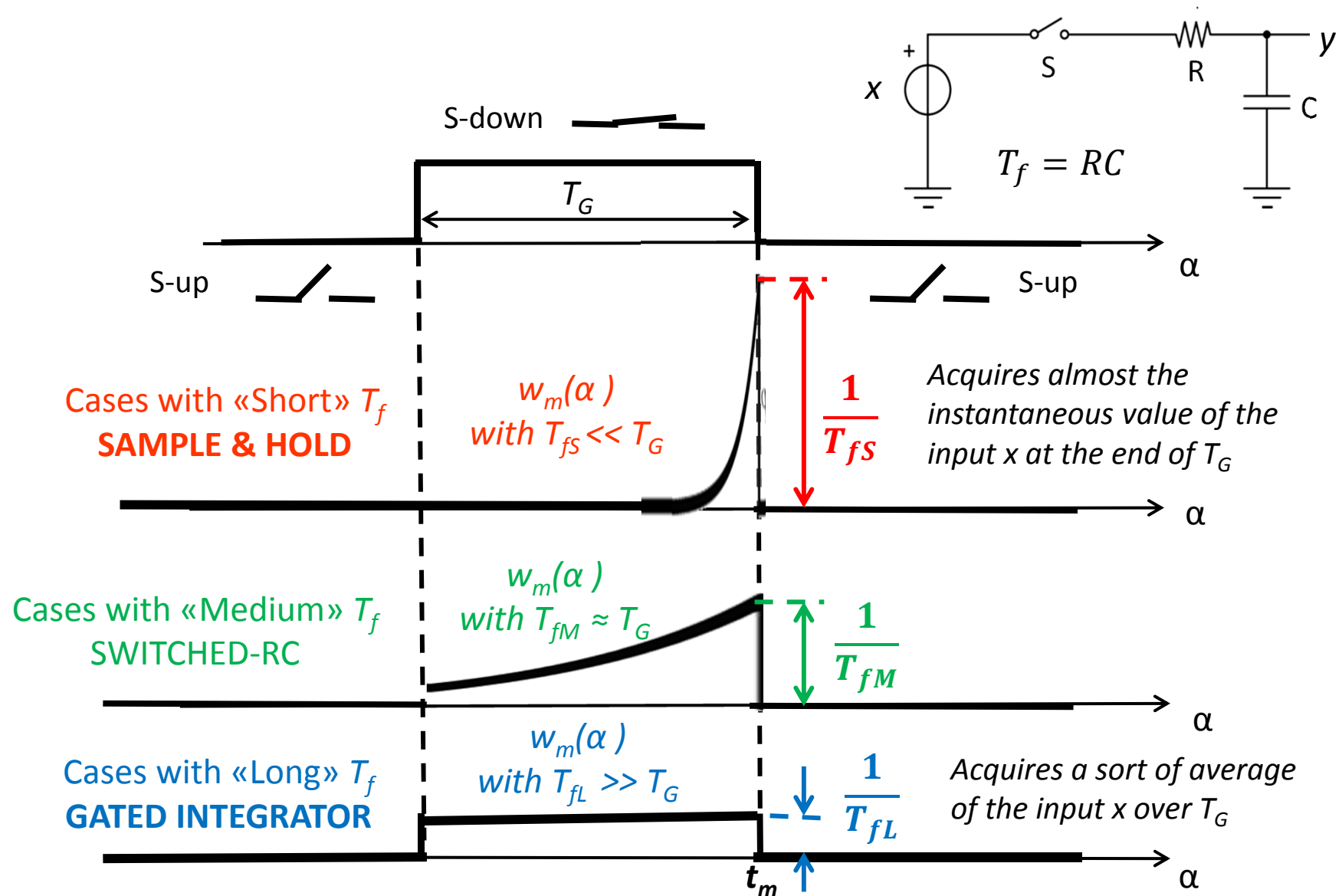
Switched-parameter RC low-pass filters



- State with S down (closed in short circuit): the circuit behaves like a constant-parameter RC integrator; current can flow in and out of C
- State with S up (open circuit): the circuit is in HOLD, no current can flow, the charge previously stored in C is maintained, the voltage on C stays constant.
- The state of S is controlled by a known command. The series resistance is switched from R (with S closed) to practically ∞ (with S open) or vice-versa.
- In the cases here considered:
 - (a) the initial state is with S open and zero charge in C
 - (b) the command closes S in synchronism with the signal to be acquired and re-opens S after the acquisition



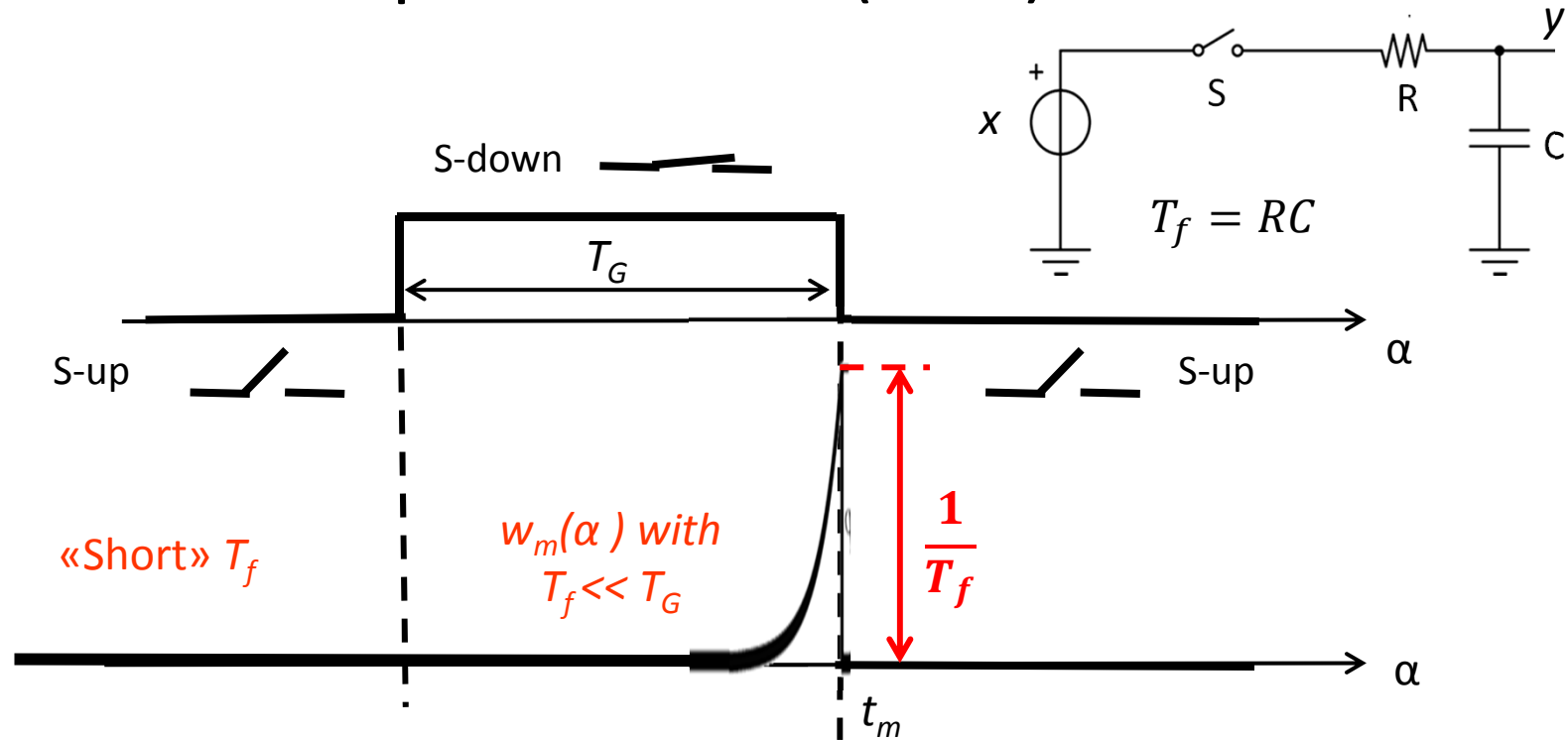
Switched-parameter RC low-pass filters



Sample and Hold S&H



Sample and Hold (S&H)



The S&H has **unity DC gain** (C is fully charged at the input voltage within T_G)

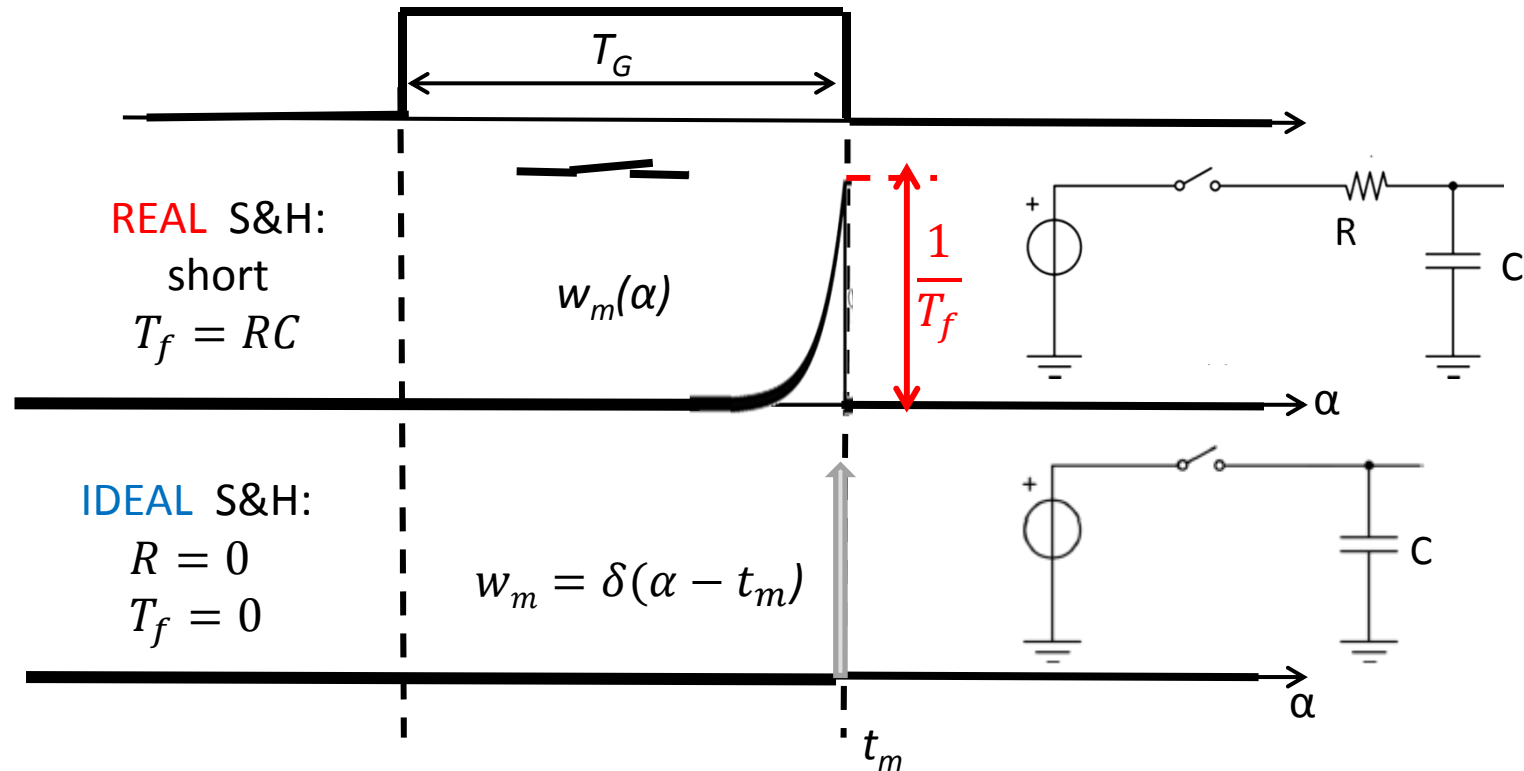
$$W_m(0) = \int_0^{\infty} w_m(\alpha) d\alpha = 1$$

The S&H has very mild filtering action, equivalent to that of a constant-parameter RC integrator with equal time constant T_{fs} . With wide-band input noise S_b (bilateral)

$$\overline{y_n^2} = S_b \cdot \frac{1}{2T_f}$$



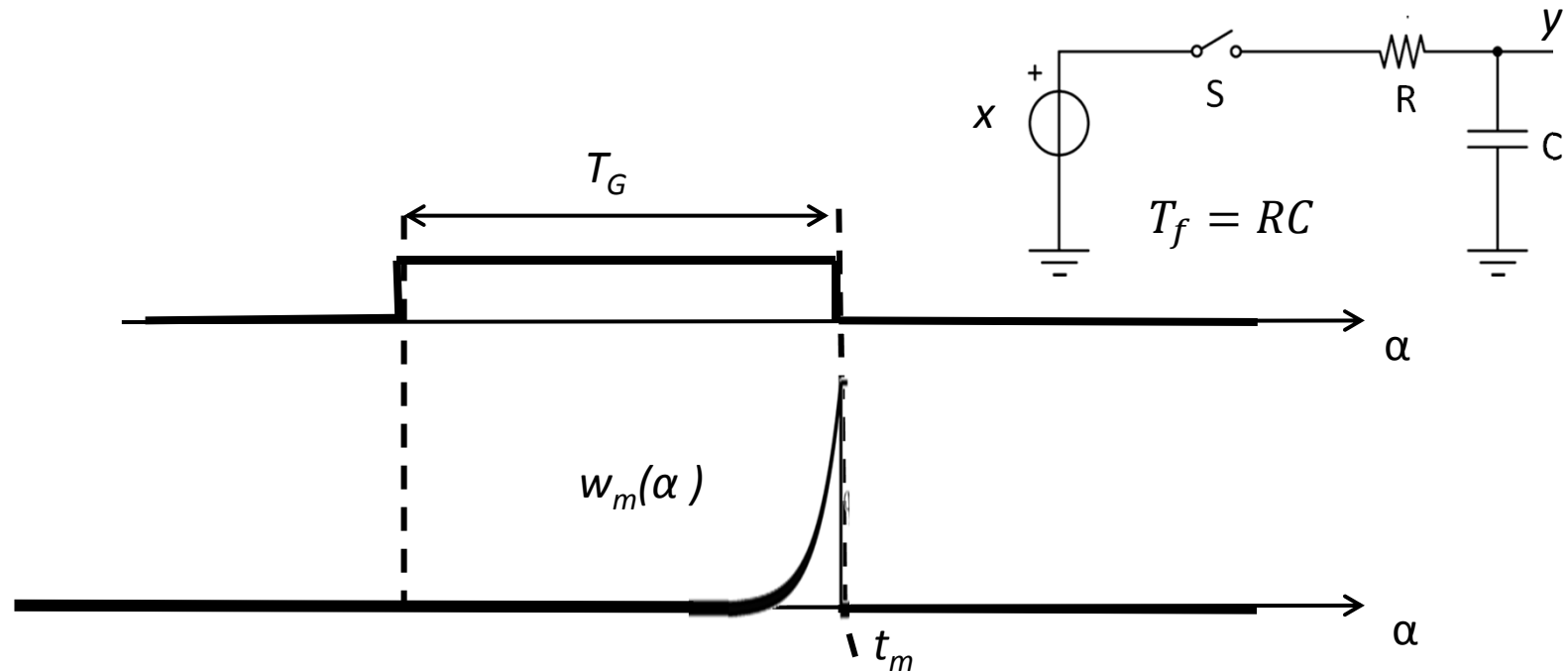
Real vs ideal S&H



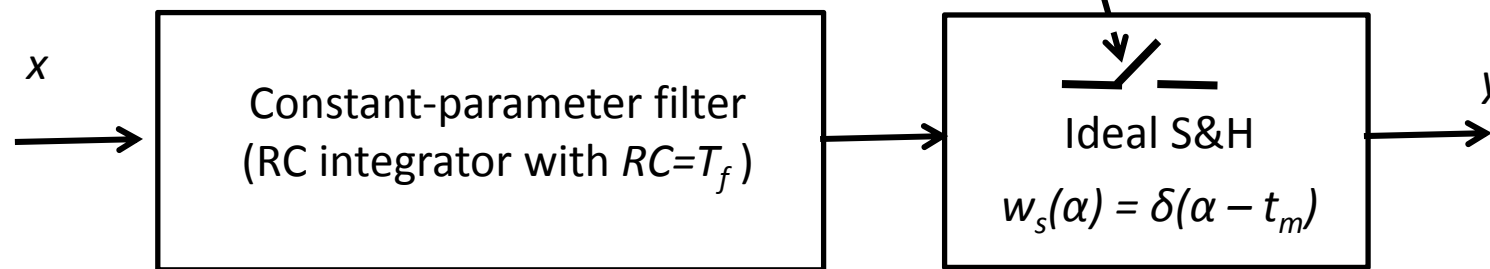
- The minimum available T_f is limited by the technology of devices and circuits (finite R values of fast switching devices and C values required for holding information)
- S&H acquisition time = time for reaching the full output value \approx a few T_f , i.e. currently some tens of nanoseconds in discrete-component circuits
some tens of picoseconds in integrated circuits with minimized capacitances



S&H equivalent model



The output of a real S&H is equivalent to (and can be modeled as) the cascade of two stages:



S&H Readout Noise

- READOUT NOISE of a sampling circuit is the contribution to the output noise due to the internal noise sources in the sampling circuit itself
- In the S&H the main source of readout noise is the wide-band Johnson noise of R with spectral density $S_{bB} = 2kTR$ (bilateral)

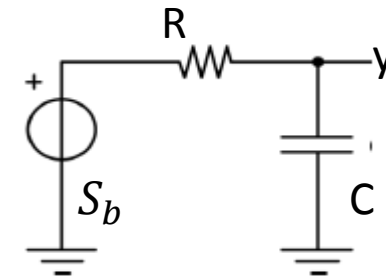
Since

$$w(\alpha) = \frac{1}{T_f} e^{-\frac{(t_m - \alpha)}{T_f}} 1(t_m - \alpha) \quad \text{and} \quad k_{ww}(\tau) = \frac{1}{2T_f} e^{-\frac{|\tau|}{T_f}}$$

the readout noise is

$$\overline{y_R^2} = S_{bB} \cdot k_{ww}(0) = 2kTR \cdot \frac{1}{2T_f} = 2kTR \cdot \frac{1}{2RC}$$

$$\boxed{\overline{y_R^2} = \frac{kT}{C}}$$



this is just the noise generated and self-filtered by a constant parameter RC filter and is INDEPENDENT OF THE R VALUE, in agreement with the S&H circuit model.

- Note that this noise can be directly compared with the input signal, because the S&H has unity DC gain, it brings to the output the full amplitude of the sampled signal



S&H Readout Noise

The equation

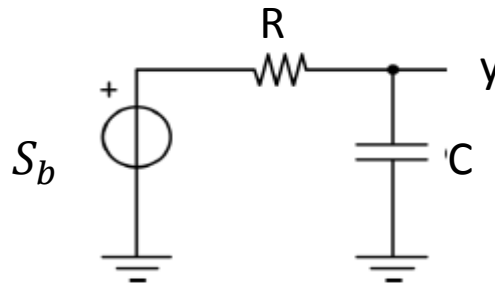
$$\overline{y_R^2} = \frac{kT}{C}$$

of the self-generated output noise of a constant parameter RC filter is consistent with the laws of thermodynamics. In fact:

- In a system in thermal equilibrium, the mean thermal energy is $\frac{kT}{2}$ for each degree of freedom;
- the RC circuit has one degree of freedom (one C, i.e, one time constant)

Therefore:

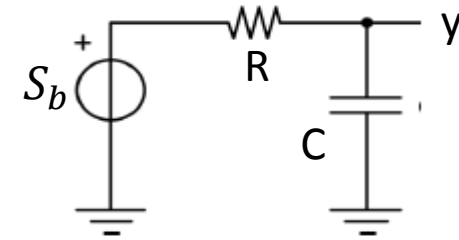
$$\frac{1}{2} C \overline{y_R^2} = \frac{kT}{2}$$



S&H Readout Noise

The **readout noise voltage** evaluated at room temperature is

$$\sqrt{y_R^2} = \sqrt{\frac{kT}{q} \frac{q}{C}} \cong \frac{63\mu V}{\sqrt{C(\text{in pF})}}$$



In various applications (e.g. CCD imaging photodetectors) the signal is not a given voltage but a given charge, to be compared with the **readout noise charge** in C

$$\overline{Q_n^2} = C^2 \overline{y_R^2} = kTC$$

In terms of number of electrons N_q the noise is (NB: $q = \text{electron charge}$)

$$\overline{N_q^2} = \frac{\overline{Q_n^2}}{q^2} = \frac{kTC}{q^2} = \frac{kT}{q} \cdot \frac{C}{q}$$

Therefore, the rms fluctuation of the electron number evaluated at room temperature is

$$\sqrt{\overline{N_q^2}} = \sqrt{\frac{kT}{q} \cdot \frac{C}{q}} \cong 125 \cdot \sqrt{C[\text{in pF}]} \text{ electrons}$$

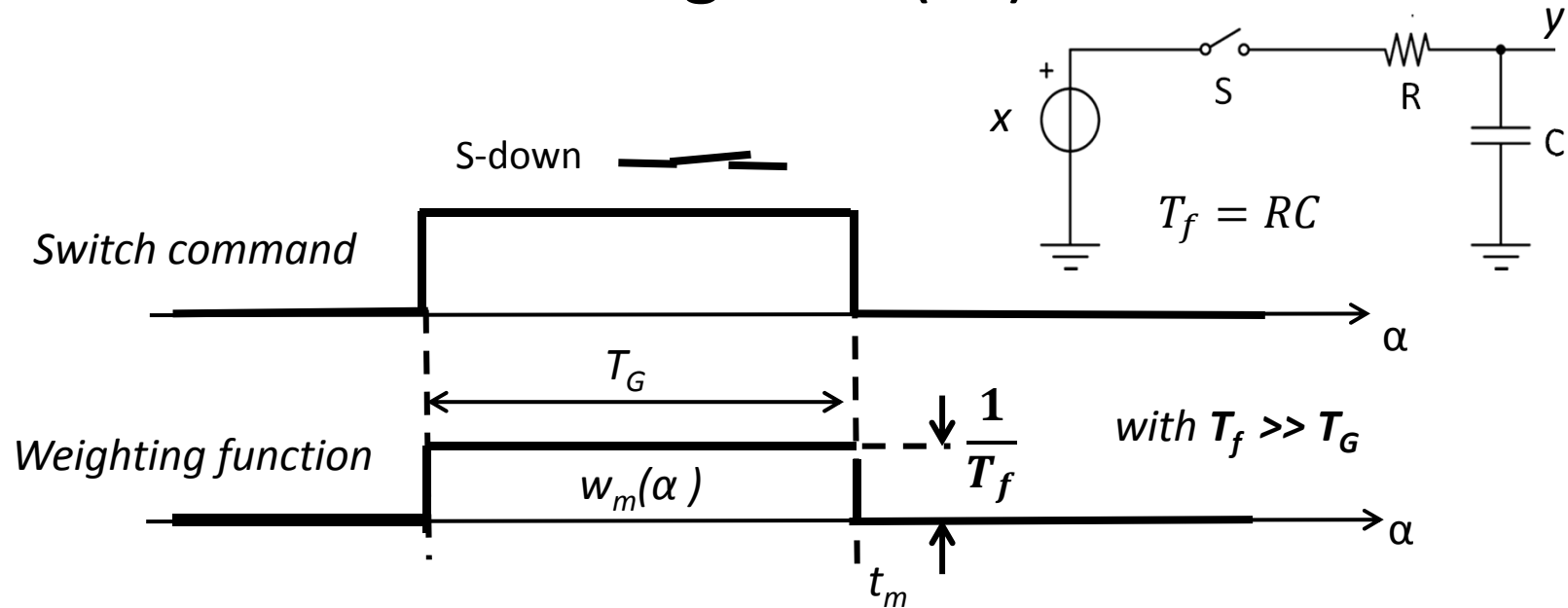
e.g. with $C = 0,1 \text{ pF}$ the rms is about 40 electrons



Gated Integrator GI



Gated Integrator (GI)



- For behaving as GI (uniform weight in T_G) the circuit must have $T_f \gg T_G$

- Therefore, the **DC gain G is inherently much less than unity**

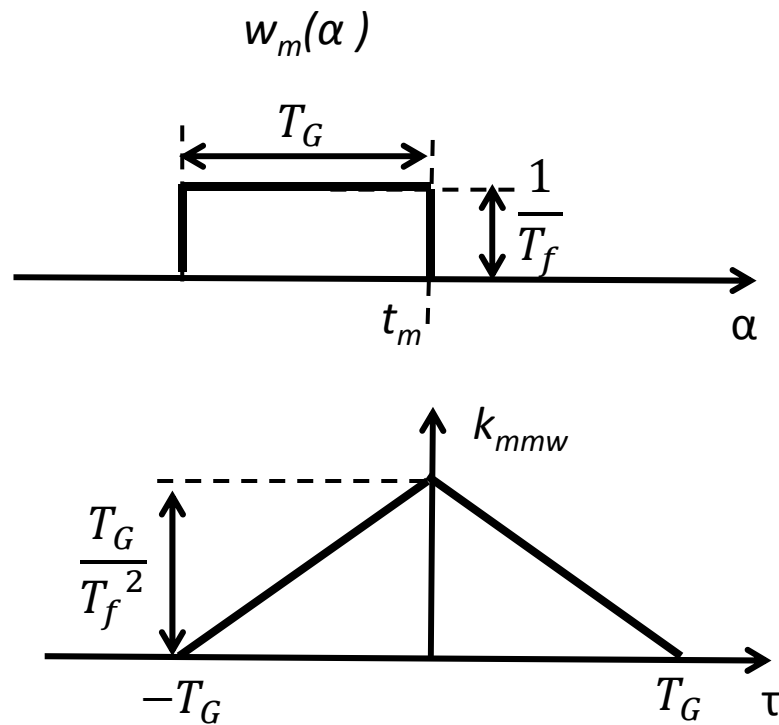
$$G = W_m(0) = \int_0^{\infty} w_m(\alpha) d\alpha = \frac{T_G}{T_f} \ll 1$$

- A GI has remarkable filtering action on a wide-band input noise, that is, on noise with autocorrelation width much shorter than the gate duration T_G .
- Long gate duration T_G is well feasible in practice, much better than a long averaging interval T_a in a mobile-mean filter

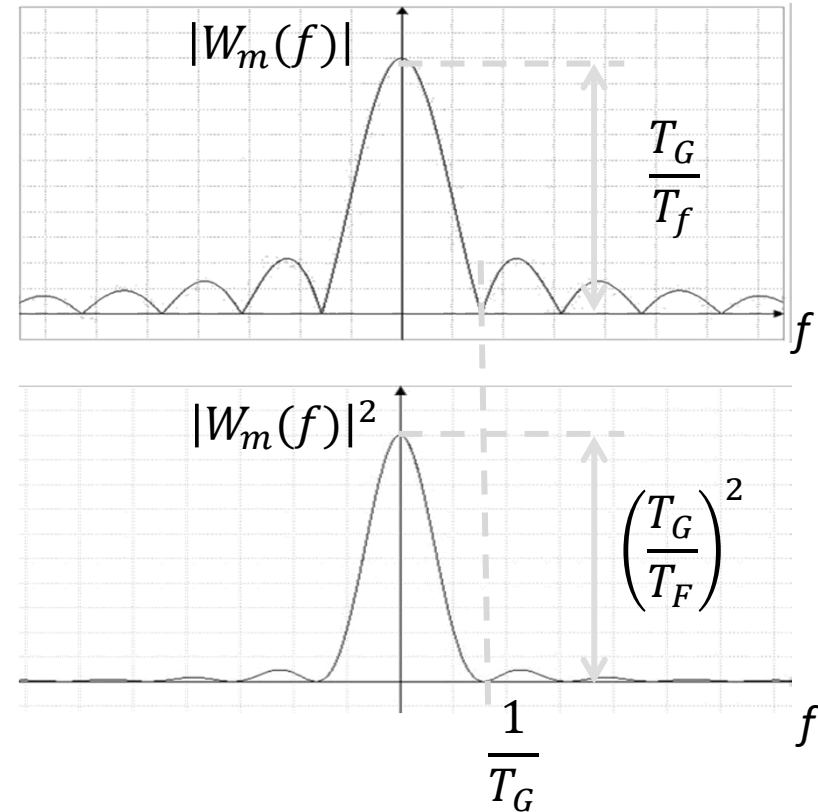


Gated Integrator (GI)

TIME DOMAIN



FREQUENCY DOMAIN



$$W_m(f) = \frac{T_G}{T_f} \cdot \frac{\sin \pi f T_G}{\pi f T_G}$$



Filtering and S/N enhancement by GI

INPUT:

- signal x_s constant in T_G (DC signal)
 - wide-band noise S_b (bandwidth $f_n \gg 1/T_G$ and autocorrelation width $T_n \ll T_G$)
- $$\overline{x_n^2} = S_b 2f_n = S_b / 2T_n$$

OUTPUT:

Signal $y_s = x_s \cdot \frac{T_G}{T_f} = x_s G$ i.e. with gain $G = \frac{T_G}{T_f} \ll 1$

Noise $\overline{y_n^2} = S_b \cdot \frac{T_G}{T_f^2} = \frac{S_b}{T_G} \cdot \left(\frac{T_G}{T_f}\right)^2 = \frac{S_b}{T_G} \cdot G^2 =$

$$= \frac{S_b}{2T_n} \frac{2T_n}{T_G} G^2 = \overline{x_n^2} \cdot \frac{2T_n}{T_G} \cdot G^2$$

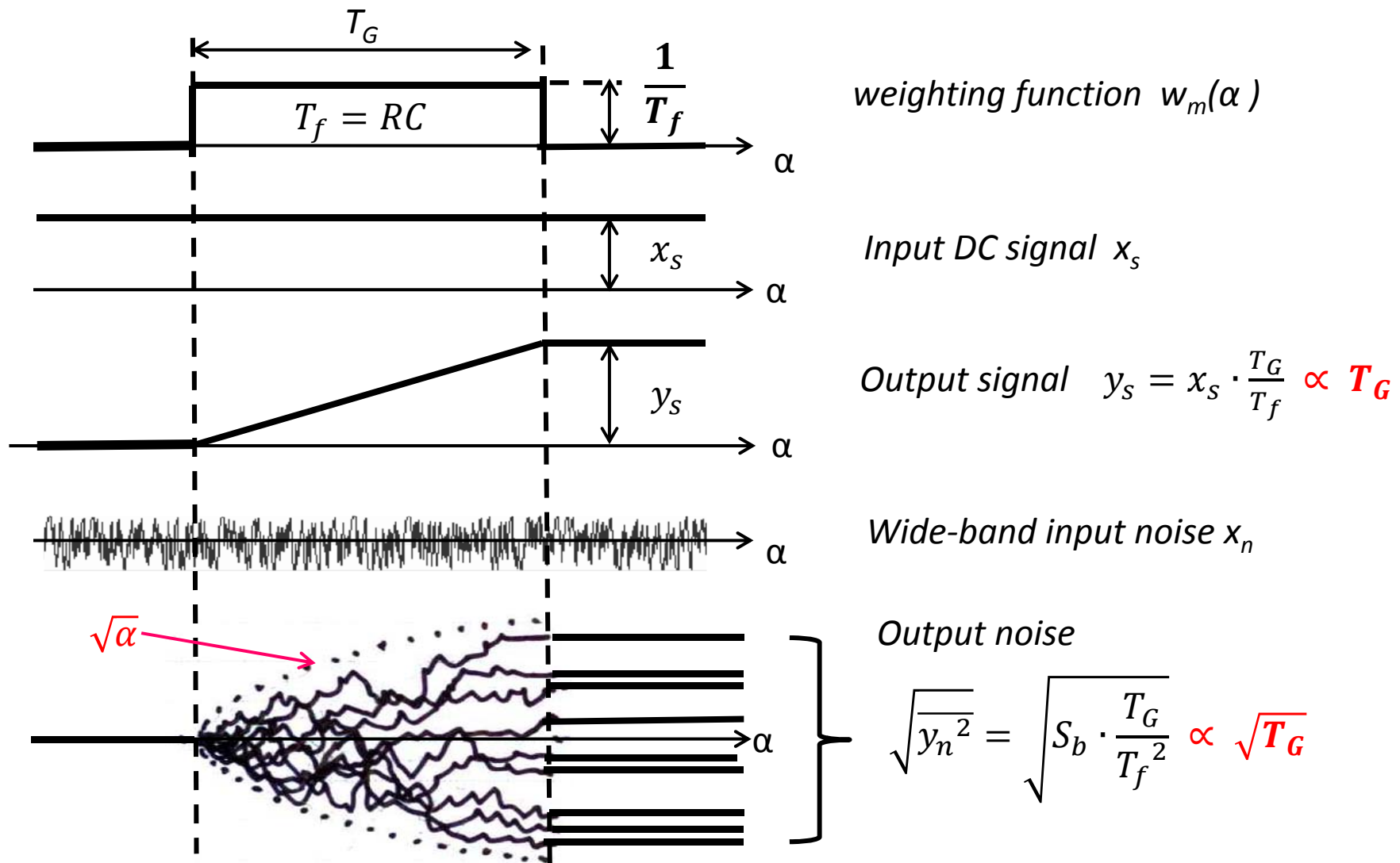
Signal-to-noise ratio

$$\left(\frac{S}{N}\right)_y = \frac{y_s}{\sqrt{\overline{y_n^2}}} = \frac{x_s}{\sqrt{\overline{x_n^2}}} \cdot \sqrt{\frac{T_G}{2T_n}} = \left(\frac{S}{N}\right)_x \cdot \sqrt{\frac{T_G}{2T_n}}$$

NB: the output signal increases as T_G and the noise as $\sqrt{T_G}$, therefore the S/N increases as the square root of the gate time $\sqrt{T_G}$



Output Signal and Noise of GI



Gaining Insight in the GI output noise

- Poisson Noise model: two random sequences of elementary pulses with positive and negative polarity and equal rate $n_+ = n_- = n$
- White input noise: the elementary pulses are δ -like with area $+q$ and $-q$
- Output noise of the GI: the elementary pulses are steps with amplitude $+q$ and $-q$
- Mean numbers of pulses in T_G :
positive $\overline{N}_+ = n_+ T_G$ and negative $\overline{N}_- = n_- T_G$; therefore $\overline{N}_+ = \overline{N}_- = N = nT_G$
- Fluctuating output amplitude : $y_n = N_+q - N_-q$ (with mean value $\overline{y_n} = 0$)
- Mean square numbers of pulses in T_G (Poisson statistics): $\overline{N_+^2} = \overline{N_-^2} = N$
- **Mean square** amplitude of the output noise
$$\overline{y_n^2} = \overline{N_+^2}q^2 + \overline{N_-^2}q^2 = 2Nq^2 = 2nq^2 \cdot T_G$$
- **Root-mean-square** amplitude of the output noise

$$\sqrt{\overline{y_n^2}} = q\sqrt{2nT_G} \propto \sqrt{T_G}$$



GI compared to other LPF

Fair comparison between different LPF with different DC gain G can be made by considering the value of the **filtered noise referred to the input** of the filter (and the input signal). This is equivalent to consider the **output with unity DC gain** (if necessary, by considering to add further gain stages).

For a GI this noise is

$$\overline{(x_n^2)}_{GI} = \frac{\overline{(y_n^2)}_{GI}}{G^2} = \frac{S_b}{T_G}$$

For a constant-parameter RC (inherently with $G=1$) that filters the same wide-band noise S_b it is

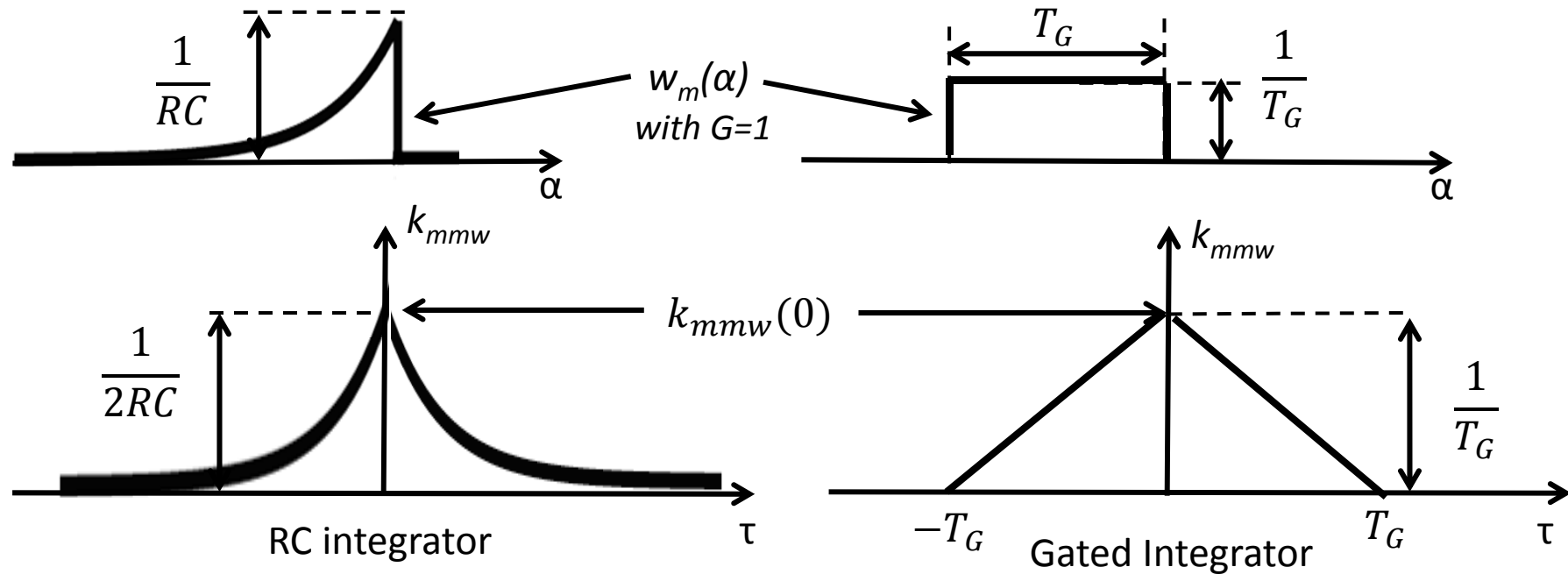
$$\overline{(x_n^2)}_{RC} = \overline{(y_n^2)}_{RC} = \frac{S_b}{2RC}$$

Therefore, as concerns the S/N obtained for input DC signals accompanied by wide-band noise, GI and RC integrator are equivalent if

$$T_G = 2RC$$



GI and equivalent RC-integrator



We consider here filters with **equal DC gain of unity**, hence with equal output signal.

With wide-band input noise S_b the output noise is

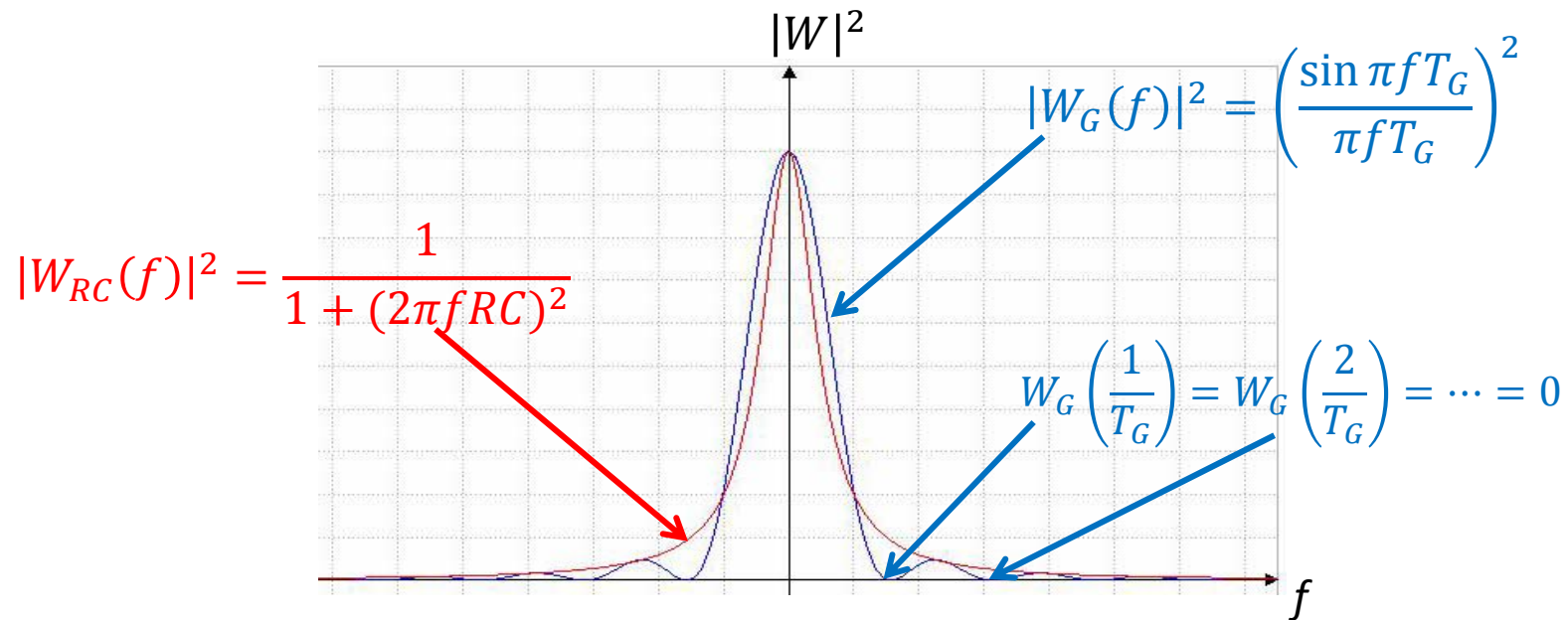
$$\overline{y^2} = S_b \cdot k_{mmw}(0)$$

therefore, GI and RC have **equal output noise** if

$$T_G = 2RC$$



GI and equivalent RC-integrator



With $T_G = 2RC$ they are equivalent for:

- the S/N obtained with wide-band noise and DC signal input
- the attenuation of high-frequency disturbances in general

However:

- The GI has **zeros of $W_G(f)$** at $f_k = k/T_G$ that can be exploited to cancel specific disturbances at known frequencies (radio frequencies or mains frequency and harmonics)



GI as fast sampler - Readout Noise

Ultrafast samplers that acquire signals in time intervals much shorter than the acquisition times of S&H are in fact gated integrators with ultrashort gate time T_G . Consequently they have DC gain much smaller than unity $G \ll 1$, **typically $G \approx 0,01$** .

The READOUT NOISE of such GI-samplers has the same source as the S&H (the Johnson noise $S_b = 2kTR$ of the internal resistance R) but it has a much stronger effect. The readout noise at the **GI-sampler output** is

$$\overline{y_n^2} = S_b \frac{T_G}{T_f^2} = 2kTR \frac{T_G}{T_f^2} = 2 \frac{kT}{C} G \quad (\text{with } T_f = RC)$$

but the **noise referred to the input** is

$$\frac{\overline{y_n^2}}{G^2} = \frac{S_b}{T_G} = \frac{kT}{C} \cdot \frac{2}{G}$$

which because of the very low G value is **much higher than that of a S&H**

$$\frac{\overline{y_n^2}}{G^2} = \frac{kT}{C} \cdot \frac{2}{G} \gg \frac{kT}{C} \quad \text{typically} \quad \frac{\overline{y_n^2}}{G^2} \approx 100 \frac{kT}{C}$$

